

INTERFACE CIRCUIT – RELAY AND LAMP – DRIVER

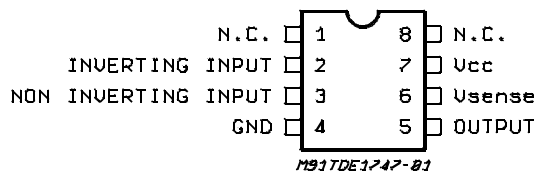
- OPEN GROUND PROTECTION
- HIGH OUTPUT CURRENT
- ADJUSTABLE SHORT-CIRCUIT PROTECTION TO GROUND
- THERMAL PROTECTION WITH HYSTERESIS TO AVOID THE INTERMEDIATE OUTPUT LEVELS
- LARGE SUPPLY VOLTAGE RANGE : + 10 V TO + 45 V
- SHORT-CIRCUIT PROTECTION TO V_{CC}

DESCRIPTION

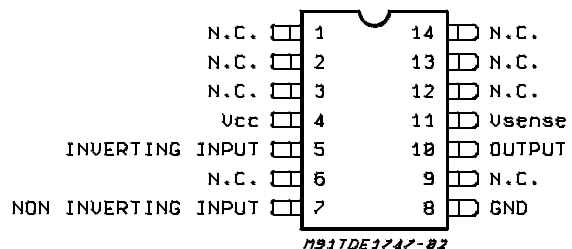
The TDE/TDF1747 is a monolithic comparator designed for high current and high voltage applications, specifically to drive lamps, relays, stepping motors.

This device is essentially blow-out proof. Current limiting is available to limit the peak output current to safe values, the adjustment only requires one external resistor. In addition, thermal shut down is provided to keep the I.C. from overheating. If internal dissipation becomes too great, the driver will shut down to prevent excessive heating. TDE1747 has an open ground protection. The output is also protected from short-circuits with the positive power supply.

PIN CONNECTIONS (Top view)



Minidip



SO14

The device operates over a wide range of supply voltages from standard ± 15 V operational amplifier supplies down to the single + 12 V or + 24 used for industrial electronic systems.

ABSOLUTE MAXIMUM RATINGS

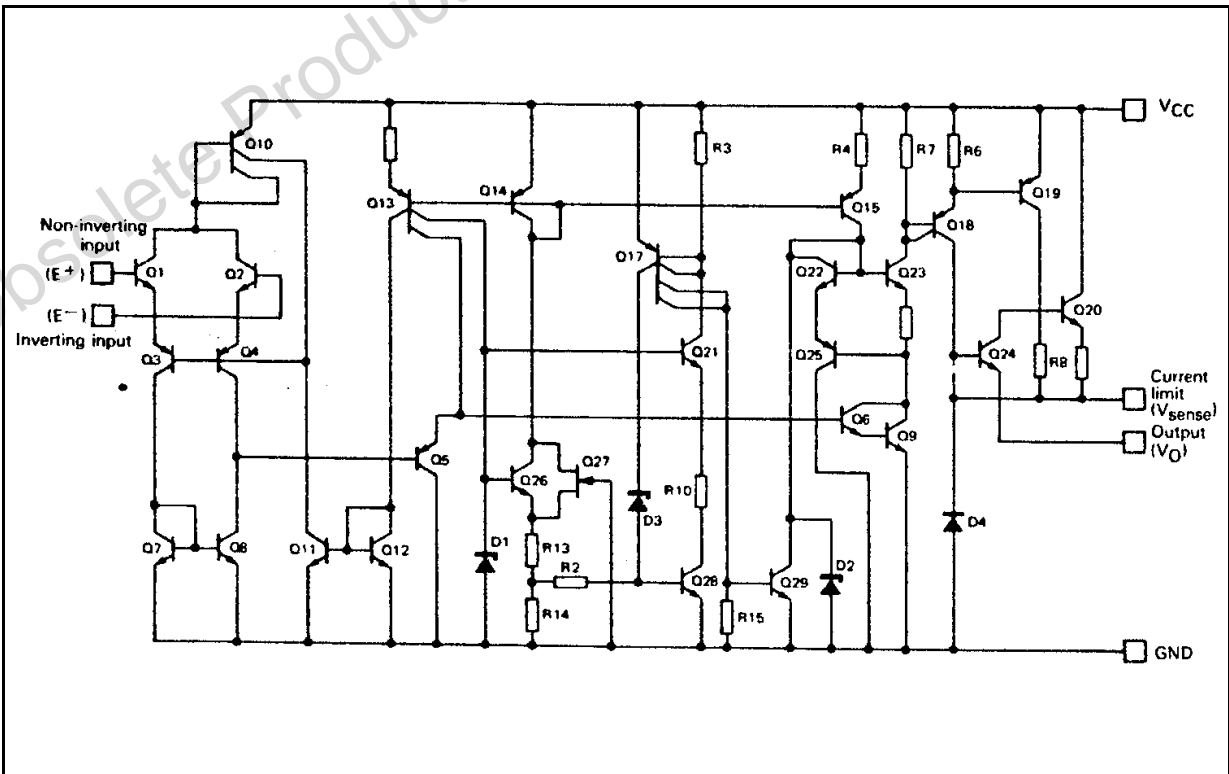
Symbol	Parameter	Value	Unit
V _{CC}	Supply Voltage	50 *	V
V _{ID}	Differential Input Voltage	50	V
V _I	Input Voltage	50	V
I _O	Output Current	1	A
P _{tot}	Power Dissipation (T _{amb} = + 25 °C)	Internally Limited	W
T _{stg}	Storage Temperature Range	– 65 to + 150	°C
T _{oper}	Operating Ambient Temperature Range TDE1747 TDF1747	– 25 to + 85 – 40 to + 85	°C °C

(*) 60V, t â 10ms

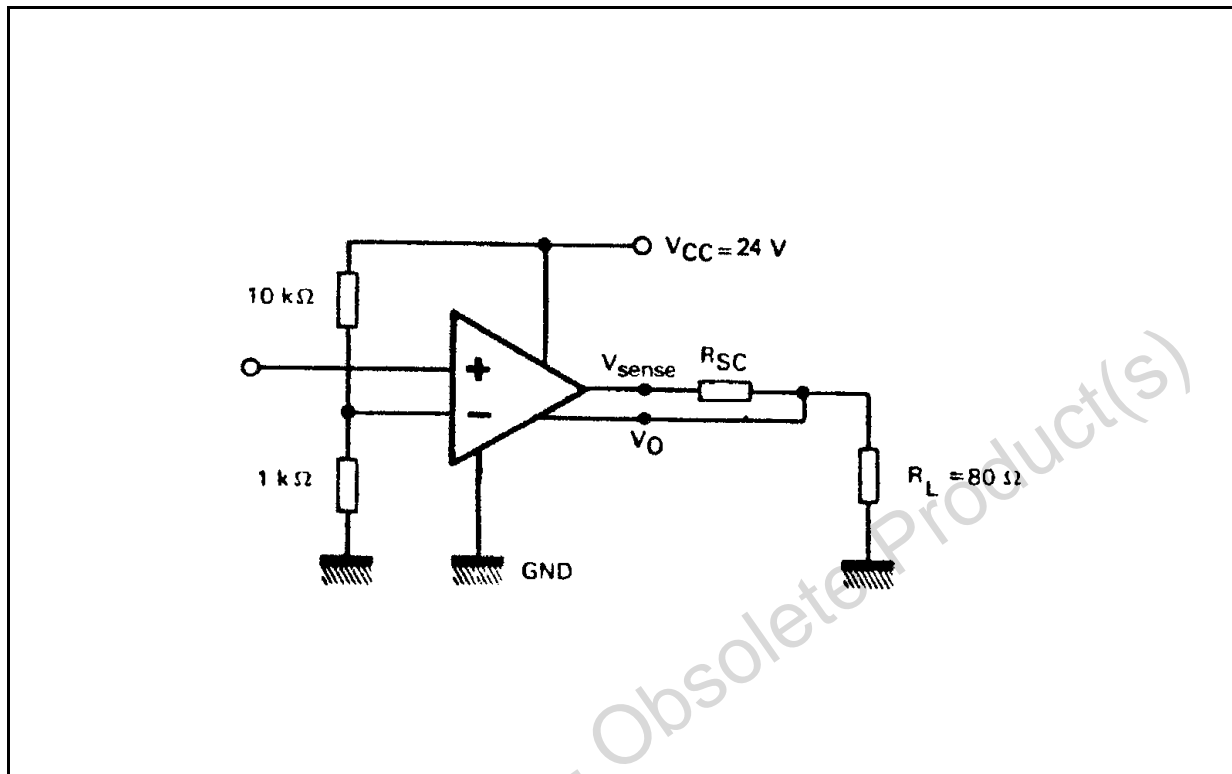
THERMAL CHARACTERISTICS

Symbol	Parameter	Value	Unit
R _{th(j-c)}	Maximum Junction-case Thermal Resistance	50	°C/W
R _{th(j-a)}	Maximum Junction-ambient Thermal Resistance	120	°C/W
R _{th}	Junction-ceramic Substrate (case glued to substrate) SO14	90	°C/W
R _{th}	Junction-ceramic Substrate (case glued to substrate, substrate temperature maintained constant) SO14	65	°C/W

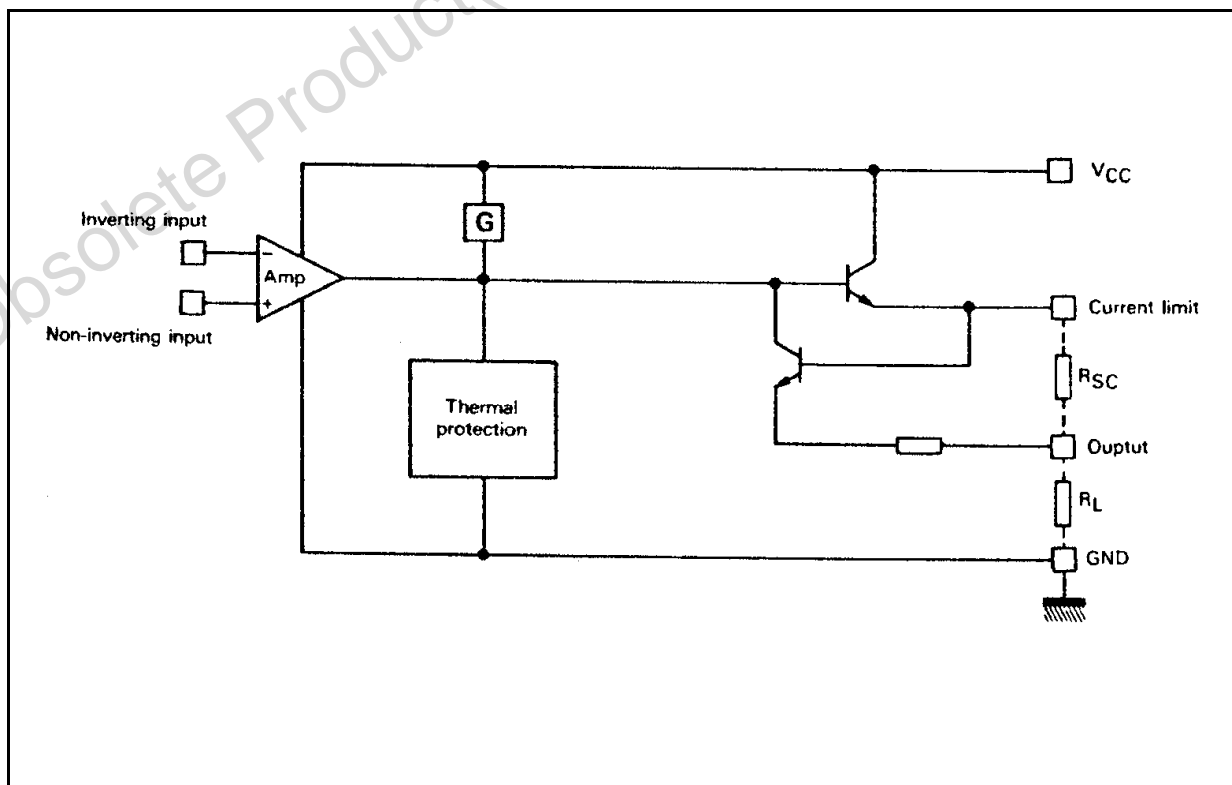
SCHEMATIC DIAGRAM



TEST CIRCUIT



SIMPLIFIED CIRCUIT



ELECTRICAL CHARACTERISTICS $T_j = -25$ to $+85$ °C, $V_{CC} = 8$ to 45 V, unless otherwise specified (note 1).

Symbol	Parameter	Min.	Typ.	Max.	Unit
V_{IO}	Input Offset Voltage - (note 2)	–	2	50	mV
I_{IB}	Input Bias Current	–	0.1	1.5	mA
I_{CC}	Supply Current ($V_{CC} = +24$ V, $I_O = 0$)				
	High Level	–	4	6	mA
	Low Level	–	2	4	mA
$V_{I(max)}$	Common-mode Input Voltage Range	2	–	$V_{CC}-2$	V
I_{SC}	Short-circuit Current Limit ($T_{amb} = +25$ °C, $V_{CC} = +24$) $R_{SC} = 1.5$ Ω $R_{SC} = \infty$	–	480	–	mA
		–	35	50	mA
$V_{CC}-V_O$	Output Saturation Voltage (output high) ($R_{SC} = 0$, $V_I+V_I- \geq 50$ mV) $I_O = 300$ mA, $T_j = +25$ °C $T_j = +150$ °C	–	1.15	1.4	V
		–	1.05	1.3	V
I_{OL}	Low Level Output Current ($V_O = 0$, $V_{CC} = +24$ V) $T_j = +25$ °C	–	0.01	10	μ A

Notes :

1) For operating at high temperature, the TDE/TDF1747, must be derated based on a $+150$ °C maximum junction temperature and a junction-ambient thermal resistance of 120 °C/W for Minidip and 100 °C/W for the SO14.

2) The offset voltage given is the maximum value of input voltage required to drive the output voltage within 2 V of the ground or the supply voltage.

Figure 1: Available Output Current vs. Limiting Resistor

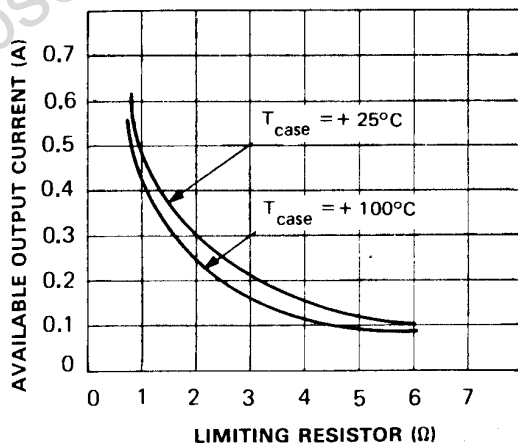


Figure 2: Peak Short-circuit Output Current vs. Limiting Resistor

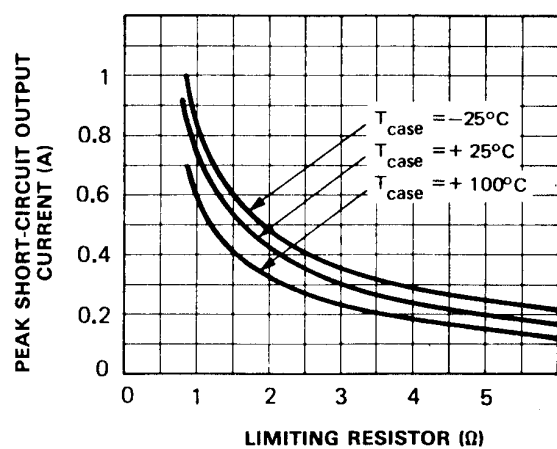


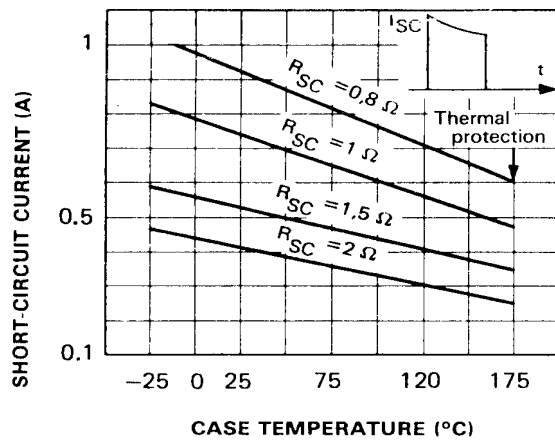
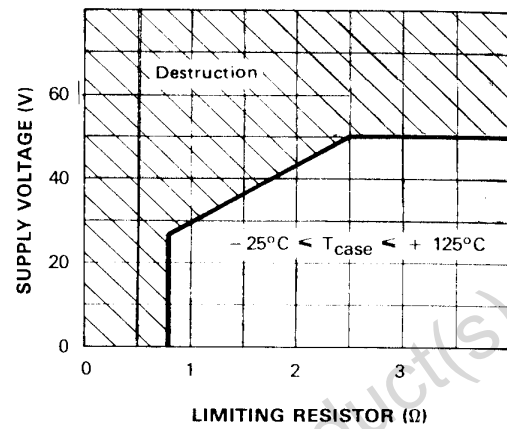
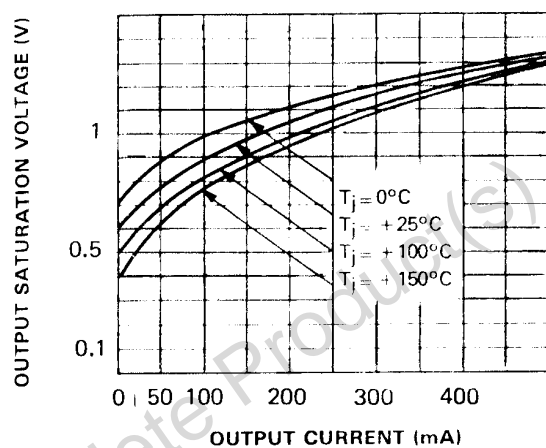
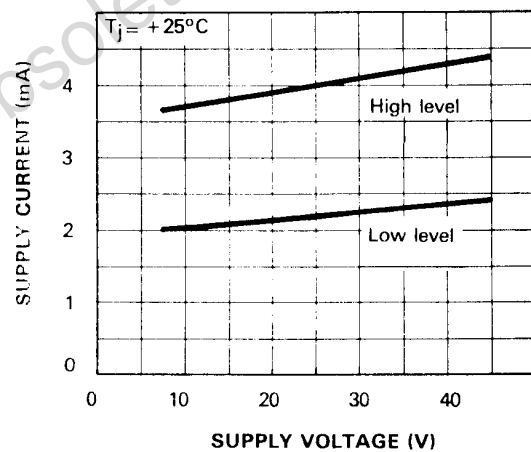
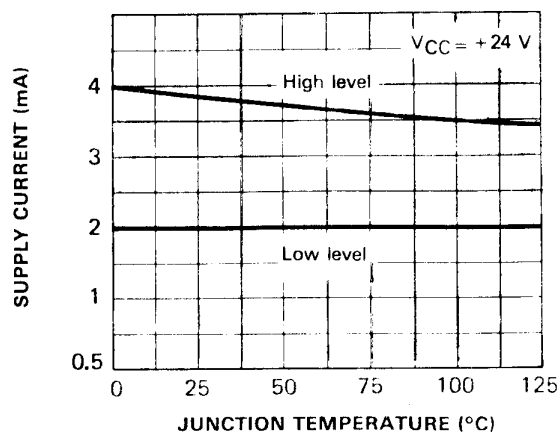
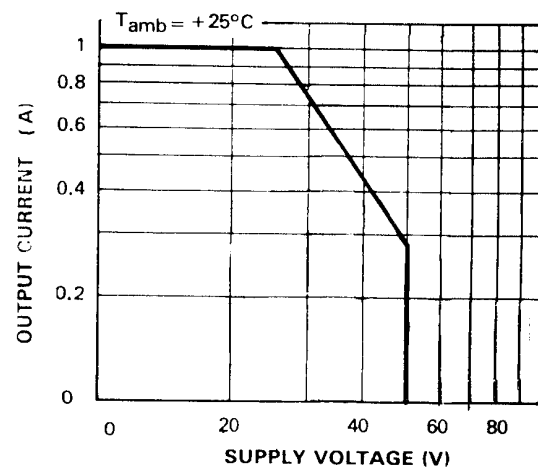
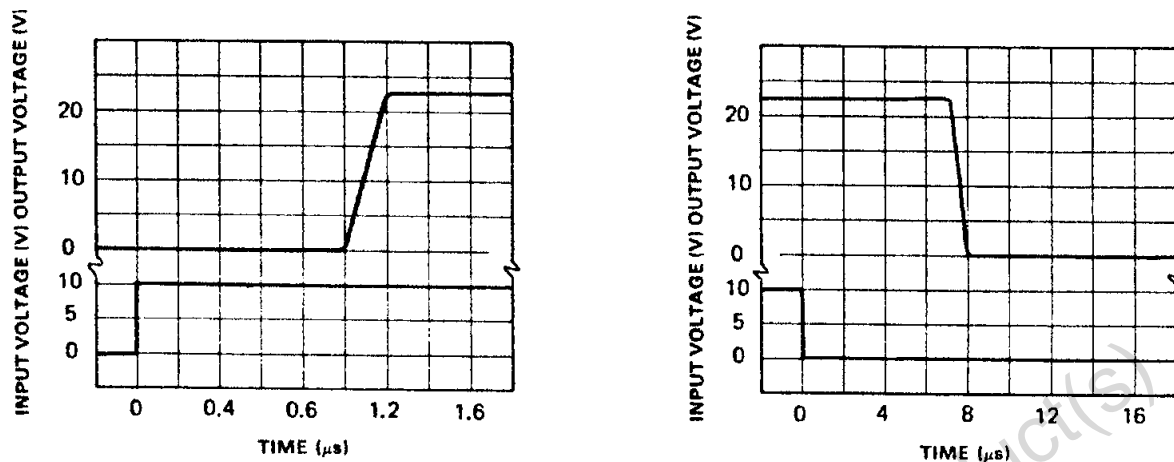
Figure 3: Short-circuit Current vs. Case Temperature**Figure 4:** Minimum Limiting Resistor Value vs. Supply Voltage**Figure 5:** Output Current vs. Output Saturation Voltage**Figure 6:** Supply Current vs. Supply Voltage**Figure 7:** Supply Current vs. Junction Temperature**Figure 8:** Safe Operating Area (non repetitive surge)

Figure 9: Response Time



TYPICAL APPLICATIONS

Figure 10: Base Circuit

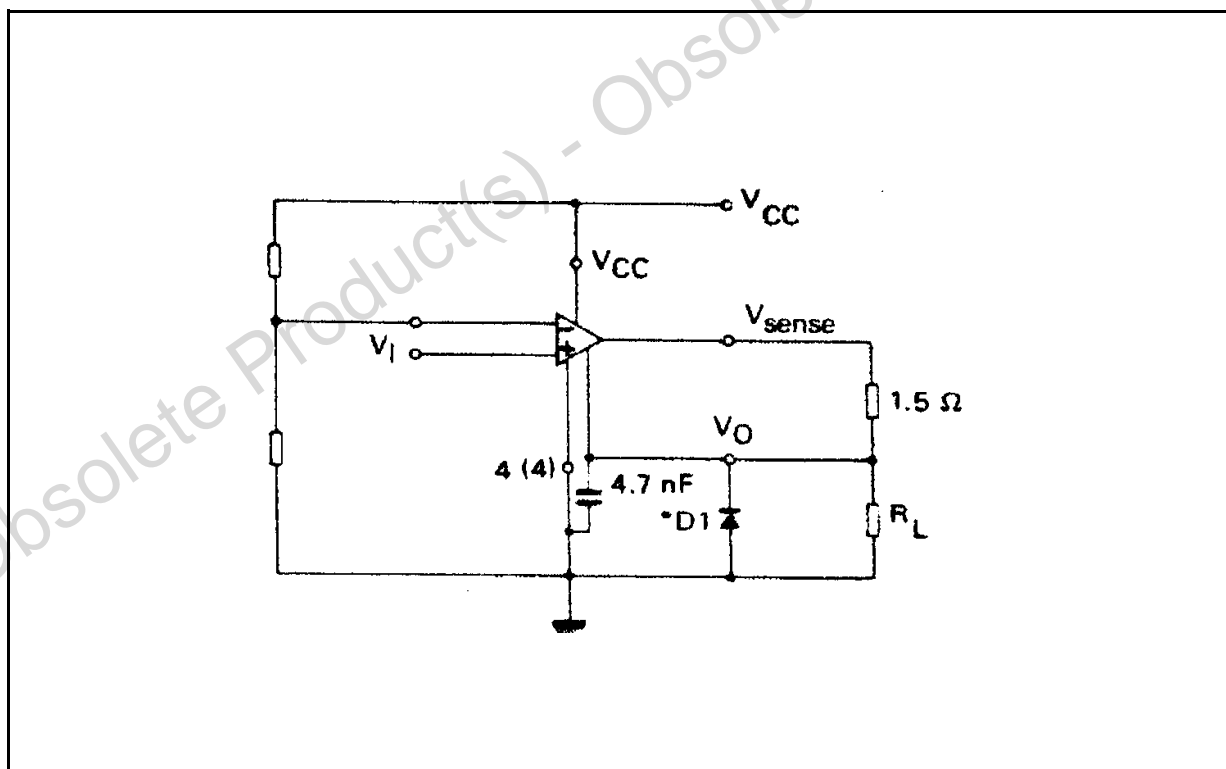
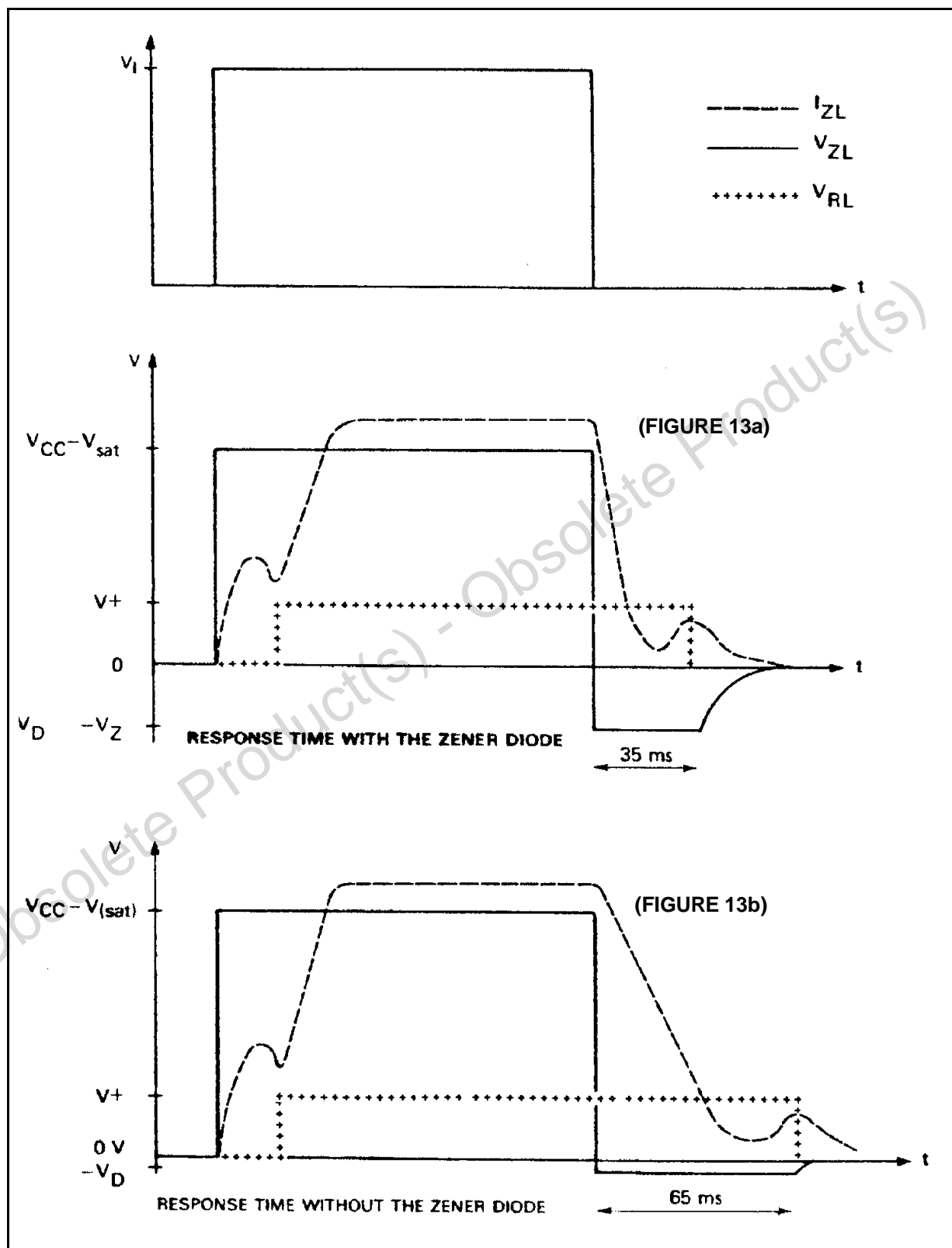
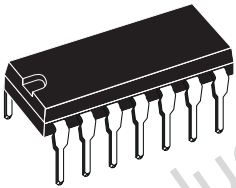


Figure 13: Waveforms

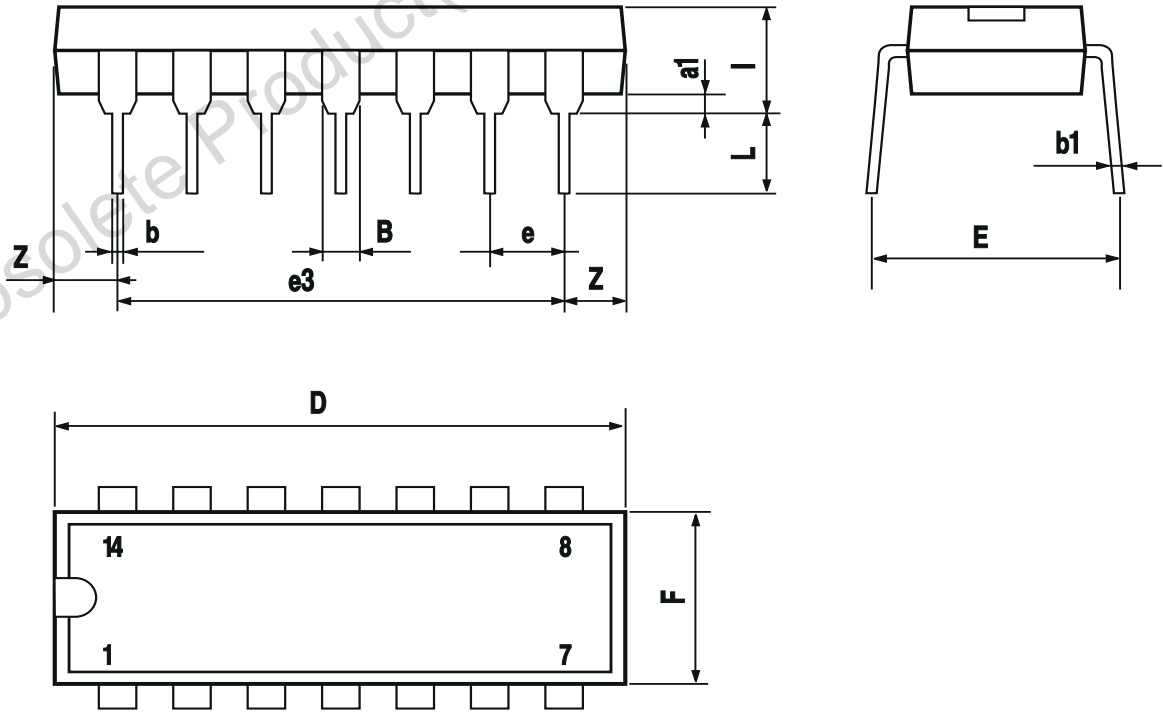


DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
a1	0.51			0.020		
B	1.39		1.65	0.055		0.065
b		0.5			0.020	
b1		0.25			0.010	
D			20			0.787
E		8.5			0.335	
e		2.54			0.100	
e3		15.24			0.600	
F			7.1			0.280
I			5.1			0.201
L		3.3			0.130	
Z	1.27		2.54	0.050		0.100

OUTLINE AND
MECHANICAL DATA



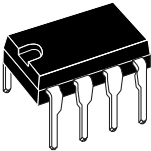
DIP14



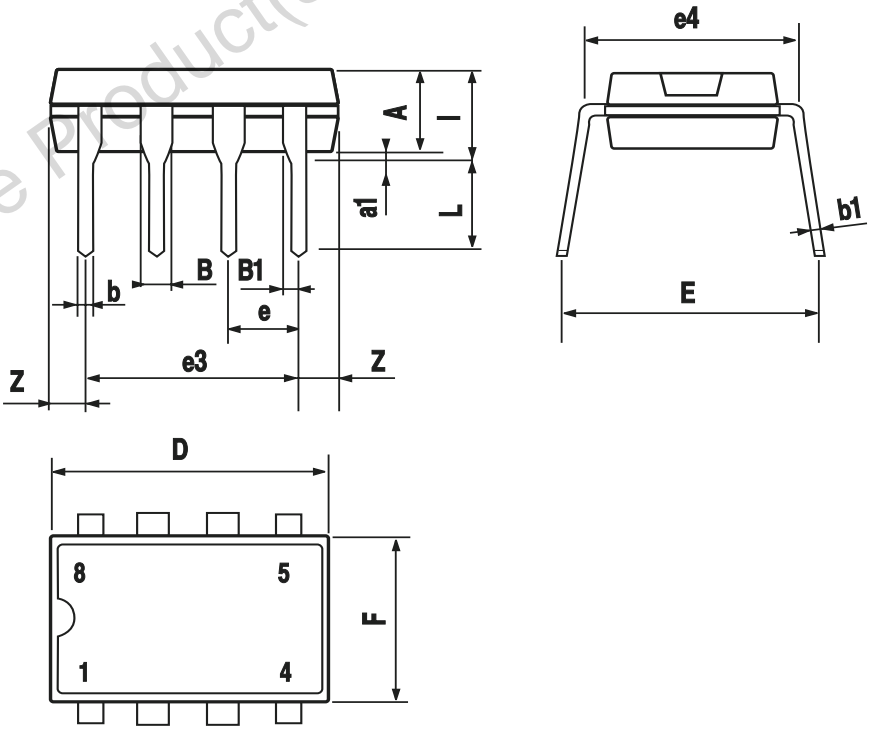
TDE1747 - TDF1747

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A		3.32			0.131	
a1	0.51			0.020		
B	1.15		1.65	0.045		0.065
b	0.356		0.55	0.014		0.022
b1	0.204		0.304	0.008		0.012
D			10.92			0.430
E	7.95		9.75	0.313		0.384
e		2.54			0.100	
e3		7.62			0.300	
e4		7.62			0.300	
F			6.6			0.260
I			5.08			0.200
L	3.18		3.81	0.125		0.150
Z			1.52			0.060

OUTLINE AND
MECHANICAL DATA



Minidip



Obsolete Product(s) - Obsolete Product(s)

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